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FLAT-PLATE SOLAR ARRAY PROJECT
ADVANCED MATERIALS RESEARCH TASK

QUARTERLY REPORT

INVESTIGATION OF THE HYDROCHLORINATION OF SICLL

(Covering the Period October 9, 1982 to January 8, 1983.)

JPL CONTRACT NO. 956061

TO

JET PROPULSION LABORATORY
CALIFORNIA INSTITUTE OF TECHNOLOGY

BY

JEFFREY Y. P. MUI

January 18, 1983.

(NASA-CR-170235) INVESTIGATION OF THE HYDROCHICRINATION OF SIC14 Quarterly Report, 9 Cct. 1982 - 8 Jar. 1583

(Solarelectronics, Inc.) 45 p HC AC3/MF AC1 Unclast CSCL 10A G3/44 C3415



The JPL Flat-Plate Solar Array Project is sponsored by the U.S. Department of Energy and forms part of the Solar Photovoltaic Conversion Program to initiate a major effort toward the development of low-cost solar arrays. This work was performed for the Jet Propulsion Laboratory, California Institute of Technology by agreement between NASA and DOE.

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FLAT-PLATE SOLAR ARRAY PROJECT

ADVANCED MATERIALS RESEARCH TASK

"Investigation of the Hydrochlorination of SiClu"

SIXTH QUARTERLY REPORT

January 18, 1983.

by

Jeffrey Y. P. Mui

SOLARELECTRONICS, INC. Bellingham, Mass.

ABSTRACT

A basic, experimental study on the hydrochlorination of silicon tetrachlori e and metallurgical grade silicon with hydrogen gas to form trichlorosilane has been carried out to greatly expand the range of reaction conditions. These reaction kinetic measuremen:s were reported in previous Quarterly Reports. During this quarter, the equilibrium constant, $K_{\mathbf{p}}$, for the hydrochlorination reaction was measured as a function of temperature, pressure and concentration. The variation of the equilibrium constant as a function of temperature provided the measurement on the heat of reaction, AH, by the Second Law Method. The value of Δ H was measured to give 10.6 Kcal/mole. The equilibrium constant was also studies as a function of concentration. In agreement with the theory, the equilibrium constant remained constant with respect to the varying H₂/SiCl_h feed ratios. On the other hand, the effect of pressure on the equilibrium constant was found to be more complex. At the lower pressure range of 25 psig to 100 psig, the equilibrium constant remained constant within experimental error. However, at the higher pressure range of 150 psig to 500 psig, the equilibrium constant showed a much higher value. This phenomenon is not

fully understood at the present time.

Previous kinetic modeling of the hydrochlorination reaction has shown that the experimental rate data obeyed a psuedo-first order kinetics. The rate constant, k_1 , for the psuedo-first order rate equation was then measured as a function of temperature, pressure and concentration. The variation of the rate constants as a function of temperature provided the measurement on the activation energy, ΔE , which was reported in the last Quarterly Report to give a value of 13.2 Kcal/mole. The effect of pressure on the rate constant was studied this quarter. The rate constant, k_1 , decreases as a function of increasing pressure. On the other hand, the concentration $(H_2/SiCl_{ij}$ feed ratio) shows a small effect on the reaction rate. The rate constant slightly increases at a higher $H_2/SiCl_{ij}$ feed ratio. An attempt to develop a generalized rate equation applicable to the entire range of reaction conditions is in progress.

Construction of the quartz hydrochlorination reactor system has been completed. This quartz reactor is designed for the deuterium kinetic isotope effect study. The reactor system has been successfully started up. Some preliminary experiments on the deuterium kinetic isotope effects were carried out. More experimental work is in progress.

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I. INTRODUCTION

A basic research and development program has been carried out to study the hydrochlorination of $SiCl_{\mu}$ and metallurgical grade (m.g.) silicon to form SiHCl3. The hydrochlorination reaction was shown to be an efficient process for the production of trichlorosilane which is an important starting material for the manufacturing of high purity, electronic grade silicon metal. Experimental work was carried out in accordance with the SC-1 Program Plan in the Appendix. The laboratory study was expanded to include a wide range of reaction conditions. These additional reaction kinetic measurements provided the needed experimental data for the subsequent theoretical studies to develop a rate equation for the hydrochlorination reaction and to provide a basic understanding on the reaction mechanism. This Quarterly Report is the sixth in the series. Activities in this quarter includes the equilibrium constant and the rate constant measurements as a function of temperature, pressure and concentration. Thermodynamic functions, such as AH, are also determined from these experimental data. Results are summarized in the following discussion.

II. DISCUSSION

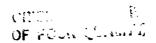
A. Equilibrium Constant Measurements

The hydrochlorination of ${\rm SiCl}_4$ and m.g. silicon to form ${\rm SiHCl}_3$ is an equilibrium reaction. The overall reaction may be written as,

$$3 \operatorname{SiCl}_{4} + 2 \operatorname{H}_{2} + \operatorname{Si} \longrightarrow 4 \operatorname{SiHCl}_{3}$$
 (1)

The equilibrium constant, K, based on mole fraction of reactants and products, is defined in accordance with the stoichiometry of the hydrochlorination reaction (1).

$$K = \frac{(\operatorname{SiRCl}_3)^4}{(\operatorname{SiCl}_4)^3 (\operatorname{H}_2)^2}$$



The activity (concentration) of elemental silicon is taken as unity. The equilibrium constant, K_p , expressed in terms of partial pressure of reactants and products, is given by,

$$K_p = \frac{(p_{SiHCl_3})^4}{(p_{SiCl_4})^3 (p_{H_2})^2}$$

The partial pressure is obtained by multiplying the mole fraction with the total pressure, P. Thus,

$$K_p = \frac{K}{p}$$

The equilibrium constants were measured as a function of temperature, concentration and pressure.

(1) Equilibrium Constant as a Function of Temperature

A series of experiments on the hydrochlorination of SiCl_L and m.g. silicon was carried out at 100 psig, H2/SiCl4 feed ratio of 2.0 and at various reaction temperatures. Sufficiently long residence times were allowed for the experiment so that the hydrochlorination reaction was well within equilibrium. The reaction product composition was then measured by the in-line gas chromatograph (G.C.) at the reaction temperature of 500 C, 525°C, 550°C and 575°C, respectively. Results of the G.C. measurements are summarized in Table I. The mole % of SiHCl $_3$ and of SiCl $_4$ in Table I was converted to mole fractions. The concentration of hydrogen in the reaction product mixture was not experimentally determined. However, it can be readily calculated. Since one mole of hydrogen is consumed for every two moles of SiHCl, produced and since one mole of hydrogen is consumed for every mole of SiH2Cl2 produced, the concentration of hydrogen at equilibrium is given by,

$$c_{H_2} = a_{H_2} - \frac{1}{2} c_{SiHCl_3} - c_{SiH_2Cl_2}$$

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where $a_{\rm H_2}$ is the initial hydrogen concentration in the feed. The values of K and K_p were calculated from the mole fraction data and from the partial pressure data obtained at equilibrium. Results are summarized in Table II. As the results in Table II show, the equilibrium constants for the hydrochlorination reaction increase as a function of increasing reaction temperature.

(2) Heat of Reaction, Δ H

The heat of reaction, $\triangle H$, is calculated by the Second Law Method. Starting from the equation,

$$\Delta F = -RT \ln K$$

by differentiation with respect to T,

$$\frac{d\Delta F}{dT} = -S$$

one obtains the well-known Van't Hoff equation,

$$\Delta H = RT^2 \frac{d \ln K}{d T}$$

where, ΔF is the Free Energy, R is the ideal gas constant, T is the temperature and S is the Entropy. By substituting $dT = -T^2 d(1/T)$, one obtains,

$$\Delta H = -R \frac{d(\ln K)}{d(\frac{1}{2})}$$

Thus, the slope of a ln K versus (1/T) plot is $-\Delta H/R$. The logarithm of the equilibrium constant K in Table II is then plotted against the inversed temperature, 1/T. Results are given in Figure I. The plot in figure I gives a straight line. The heat of reaction, ΔH , is then determined from the slope

of the straight line to give a value of 10.6 Kcal/mole for the hydrochlorination reaction. Thus, the hydrochlorination of SiCl₄ and m.g. silicon to SiHCl₃ is a slightly endothermic reaction.

(3) Equilibrium Constant as a Function of Concentration

A set of experimental data previously obtained from the hydrochlorination of SiCl_4 experiments at 100 psig, $500^{\circ}\mathrm{C}$ and at various H2/SiCl feed ratios (see Figure V, fourth Quarter y Report, April 9 to July 8, 1982) was analyzed. These experimental data are reproduced in Figure II. The equilibrium SiHCl2 conversions at various H2/SiCl4 feed ratios were directly measured from the plots at the point where the kinetic curves level off. The mole % data were converted to mole fractions as shown in Table III. The equilibrium constants, K and K_{p} , were calculated in the same manner as described in Section A (1). Results are summarized in the last two columns in Table III. The equilibrium constants in Table III remain essentially constant within experimental error at the various H2/SiCl4 feed ratios ranging from 1.0 to 4.7. The standard deviations from this set of equilibrium constant values are well within ± 10%. Thus, the equilibrium constant for the hydrochlorination reaction is constant with respect to concentration. This observation is in agreement with the theoretcial consideration.

(4) Equilibrium Constant as a Function of Pressure

The equilibrium constant, K_p, expressed in terms of partial pressures should also be a constant value with respect to pressure A collection of equilibrium data previously obtained from the hydrochlorination of SiCl₄ and m.g. silicon at 500°C and at various pressures (from 25 psig to 500 psig) and H₂/SiCl₄ feed ratios (from 1.0 to 4.7) is summarized in Table IV. The equilibrium mole% of SiHCl₃ was obtained directly from the various kinetic curves at the point where the % SiHCl₃ conversion leveled off at long residence times. These kinetic curves have been published in

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previous Quarterly Reports and in the work carried out at the Massachusetts Institute of Technology (1). The mole % data were converted to mole fractions and partial pressures. The values of K and $K_{_{\mbox{\scriptsize D}}}$ were then calculated and listed in the last two columns in Table IV. Results in Table IV show that the effect of pressure on the equilibrium constant $K_{\mathbf{p}}$ is rather complex. At the lower pressure range of 25 psig to 100 psig, the value of K_p remains constant at about 0.65 x 10⁻³ atm. -1. However, at the higher pressure range of 150 psig to 500 psig, the value of K_p increases by a factor of two or more, e.g., 1.3 x 10^{-3} atm. 1 at 500 psig. The reason for the increase of the value of K_n at the higher pressure range is not fully understood at the present time. Nevertheless, the variation of K with respect to pressure is reproducible by similar experiments on the hydrochlorination reaction at a lower temperature. Table V summarizes the results of the equilibrium constant measurements at 450°C and at the similar ranges of pressures and H2/SiCl4 feed ratio. At the lower pressure range of 25 psig to 100 psig, the value of K_n remains constant within experimental error at about 0.35 x 10^{-3} atm.⁻¹. Again, at the higher pressure range of 150 psig to 500 psig, the values of K_p increase to a much higher number, e.g., 0.66 \times 10⁻³ atm.⁻¹ at 500 psig.

B. Rate Constant Measurements

The experimental rate data obtained from the hydrochlorination of SiCl₄ and m.g. silicon was found to obey the psuedo-first order kinetics. The psuedo-first order rate equation for the hydrochlorination reaction was described in the last Quarterly Report.

$$\operatorname{SiCl}_{4} \xrightarrow{k_{1}} \operatorname{SiHCl}_{3}$$

$$\ln \frac{x_e}{x_e - x} = \frac{k_1 a}{x_e} t$$

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where x is the concentration (or partial pressure) of SiHCl₃ at time t, x_e is the concentration of SiHCl₃ at equilibrium and a is the initial concentration of SiCl₄ in the feed. A plant the logarithm of x_e/x_e - x versus time t gives a straight if the experimental rate data obey the psuedo-first order kinetics. The rate constant, k_1 , is then determined from the slope of the straight line, which equals to k_1 a/ x_e .

(1) Rate Constant as a Function of Temperature

The effect of temperature on the psuedo-first order rate constant, k_1 , was reported in the last Quarterly Report. The variation of k_1 with respect to reaction temperature provided a measurement on the activation energy, ΔE , for the hydrochlorination reaction by plotting the logarithm of k_1 versus the inversed temperature, 1/T, in the Arrhenius equation. The value of ΔE was found to be 13.2 Kcal/mole. The effect of concentration $(H_2/SiCl_{l_1}$ feed ratio) and pressure on the reaction rate was studied this quarter.

(2) Rate Constant as a Function of Concentration

A set of rate data obtained from the hydrochlorination of SiCl₄ and m.g. silicon at 100 psig, 500°C and at various H₂/SiCl₄ feed ratios (1.0 to 4.7) was analyzed by the psuedo-first order kinetics. These experimental data are shown by the kinetic curves in Figure II. The % SiHCl₃ conversions at various residence times of 10, 20, 30, 40 and 60 seconds were directly measured from these kinetic curves. The mole % conversion data were converted to mole frations and partial pressures as summarized in Table VI, Table VII, Table VIII and Table IX for the experiments with the H₂/SiCl₄ feed ratio of 4.7, 4.0, 2.8, 2.0 and 1.0, respectively. The equilibrium composition of SiHCl₃, x_e, was taken at the point where the kinetic curves leveled off. The initial partial pressure of SiCl₄, a, was calculated from the composition of the H₂/SiCl₄ feed. The logarithm of x_e/x_e-x was calculated from the partial pressure data and platted against the reaction time t as shown

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in Figure III, Figure IV, Figure V, Figure VI and Figure VII for the experiments with the $\rm H_2/SiCl_{ij}$ feed ratio of 4.7, 4.0, 2.8, 2.0 and 1.0, respectively. Results in these Figures show that a straight line was obtained in each of the plot. The rate constant, $\rm k_1$, was calculated from the slope of the straight line, which equaled to $\rm k_1a/x_e$. Results are summarized in Table XI. Data in Table XI show that the rate constant slightly increases at a higher $\rm H_2/SiCl_{ij}$ feed ratio. These results suggest that the hydrochlorination of $\rm SiCl_{ij}$ and m.g. silicon to $\rm SiHCl_3$ proceeds at a slightly faster rate at a higher concentration of hydrogen gas.

(3) Rate Constant as a Function of Pressure

A similar theoretical treatment of the reaction kinetic data obtained from the hydrochlorination of SiCl, and m.g. silicon at various pressures was performed. A set of kinetic curves obtained at 500°C and with a H₂/SiCl₄ feed ratio of 2.0 at various pressures of 25 psig, 100 psig and 200 psig is reproduced in Figure VIII. The rate of $SiHCl_3$ formation mole% conversion) was directly read from these smooth ki _ ic curves at 10, 20, 30, 40 and 60 seconds residence time. The mole % data were converted to mole fractions and partial pressures for H_2 , $SiHCl_3$ and $SiCl_4$ and summarized in Table XII, Table XIII and Table XIV for the corresponding experiments at 25 psig, 100 psig and 200 psig, respectively. The equilibrium conversion of $SiHCl_3$, x_e , was measured at the point where the kinetic curves leveled off at long residence times. The initial SiClu partial pressure, a, was calculated from the H2/SiClu feed ratio and the reactor pressure. The logarithm of x_e/x_e-x was calculated and plotted against the reaction time t as shown in Figure IX, Figure X and Figure XI for the corresponding experiments at 25 psig, 100 psig and 200 psig respectively. A straight line was obtained from each of the plot in these Figures. The rate constant, k1, was calculated from the slope

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of the straight line, which equaled to k_1a/x_2 . Results of the rate constant measurements are summarized in Table XV. Two more data points on the rate constant at 73 psig and at 500 psig were obtained by the same reaction kinetic treatment. These experimental rate data were obtained at a slightly higher H2/SiClh feed ratio (2.8 instead of 2.0). The rate constants measured at 73 psig and at 500 psig are also summarized in Table XV. Results in Table XV show that the psuedo-first order rate constant, k₁, gradually decreases as a function of increasing pressure. The rate constants in Table XV were plotted against the pressure (in atmospheres) as shown in Figure XII. The graph in Figure XII shows that the effect of pressure on the hydrochlorination reaction rate (rate constant) is not linear. An attempt is in progress to incorporate the pressure effect into the rate equation. The ultimate goal is to develop a generalized rate equation applicable to the entire range of reaction conditions studied thus far.

C. Reaction Mechanism Study

Previous experimental studies (1) on the hydrochlorination of SiCl₄ and m.g. silicon showed that a plausible reaction mechanism may involve two stepwise reactions,

$$\operatorname{SiCl}_{4} + \operatorname{H}_{2} \xrightarrow{\operatorname{slow}} \operatorname{SiHCl}_{3} + \operatorname{HCl}_{3}$$
3 HCl + Si $\xrightarrow{\operatorname{fast}} \operatorname{SiHCl}_{3} + \operatorname{H}_{2}$

The hydrogenation of a Si-Cl bond by hydrogen to form SiHCl₃ and HCl was postulated as the slow, rate-determining step. By replacing hydrogen with deuterium in the hydrochlorination reaction, a positive kinetic isotope effect may provide useful informations on the nature of the activated complex and on the mechanism of the reaction pathway.

(1) The Quartz Hydrochlorination Reactor

Construction of the quartz hydrochlorination reactor system was completed. This quartz reactor was designed for the deuterium kinetic isotope effects study. The apparatus is schematically shown in Figure XIII. The design and operation of this quartz reactor system were described in detail in the last Quarterly Report. Instruments and flowmeters were calibrated and standardized. The reactor system was successfully started up. Hydrogen was used in the initial runs to check out the system. These initial experiments also served to "clean" and to stabilize the fresh silicon metal mass bed by consuming some silicon in the process. A series of experiments on the hydrochlorination of SiCl, and m.g. silicon with hydrogen and deuterium is planned. The relative reaction rates ortween hydrogen and deuterium will be studied as a function of temperature and H2/SiCl4 or D2/SiCl4 feed ratios. More experimental work is in progress.

D. Summary of Progress

Experimental work on the JPL Contract No. 956061 has progressed in accordance with the Program Plan. Theoretical treatment of experimental rate data on the hydrochlorination reaction was carried out for the development of a rate equation and for the determination of thermodynamic functions. Equilibrium constants for the hydrochlorination of SiCl $_{\mu}$ and m.g. silicon to SiHCl $_{3}$ were measured as a function of reaction temperature, pressure and concentration. The heat of reaction, Δ H, was determined from the change of the equilibrium constant as a function of temperature. The rate data obtained from the hydrochlorination reaction was found to obey the psuedo-first order kinetics. The rate constants for the psuedo-first order rate equation were measured as a function of temperature, pressure and concentration. Variation of the rate constants as a function of temperature provided a measurement on the

activation energy, ΔE , for the hydrochlorination reaction. More work is in progress in an attempt to develop a generalized rate equation for the hydrochlorination of SiCl₄ and m.g. silicon to include the entire range of reaction conditions studied so far. Construction of the quartz hydrochlorination reactor system has been completed. This quartz reactor was successfully started up. Experiments on the deuterium kinetic isotope effects are in progress.

III. PROJECTED SEVENTH QUARTER ACTIVITIES

Planned activities for the seventh quarter (January - March) include,

- complete the experiments on the deuterium kinetic isotope effects study,
- complete the theoretical treatment of the reaction kinetic data obtained from the hydrochlorination reaction.
- complete the reaction mechanism study on the hydrochlorination of SiCl_h and m.g. silicon,
- Final Report.

IV. REFERENCES

(1) Final Report, JPL Contract No. 955382, "Investigation of the Hydrogenation of SiCl₄" by Jeffrey Y. P. Mui and Dietmar Seyferth, Massachusetts Institute of Technology, April 15, 1981.

V. APPENDIX

Program Plan SC-1

Table I to XV

Figure I to XIII

	Year	1961	1982	1983
	Month of Year	7 8 9 10 11 12	1 2 3 4 5 6 7 8 9 10 11 12	1
	σĘ	123456	8 9 10 11 12 13 1	19 20 21 22
H	Program Plan, Baseline Cost Estimate, Transfer Apparatus from M.I.T., Design and Construct 2" Reactor, Safety Review	7 8 9 10		
	Reaction Kinetic Measurements as a Function of T, P, C. Mass Balance, HCl Analyses	10 11 12	1 2	
III	Corrosion Study (1) Copper, Nickel, Carbon Steel, Stainless Steel, Incoloy 800H, Alloy 400, Hastelloy B-2 (2) Corrosion Mechanism: SEM Analyses	12	123	·
IV	Effect of Reactor Pressure: Reaction Kinetic Measurements, 25 to 500 psig, 350 to 500°C, H ₂ /SiCl ₄ Ratio 1.0 to 5.0		4567	
>	Reaction Kinetic Modeling of Previous Experimental Data		01 6 8	
VI	Supplemental Reaction Kinetic Measurement with Reaction Temperature to 650°C		21 11 01 6	1
VII	Equilibrium Constant Measurements at Temperature Range 350°C to 650°C		21 11 01	1
VIII	Reaction Mechanism Study: Deuterium Kinetic Isotope Effects		21 12	1
IX	Develop Rate Equation, Thermodynamic Functions, ΔE , ΔH , ΔG , etc.		ORIGI OF P	1234
×	Catalyst Study: Electronic Grade Silicon v.s. the Presence of Ni and Co Catalyst		21 OR	1 2 3
X	Effect of Impurities: Electronic Silicon v.s. the Presence of Fe and Al		ED.:4 LIAUÇ	1234
XII	Recommendations for Additional Develop- ment Work and Final Report		T." FY.	•
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Prepared by: Jeffrey Y. P. Mui , Solarelectronics, Inc.

EQUILIBRIUM COMPOSITIONS OF CHLOROSILANE PRODUCTS FOR THE HYDROCHLORINATION OF SiCl $_4$ AND M.G. SILICON METAL AT 100 PSIG, H $_2$ /SiCl $_4$ = 2.0 AND AT VARIOUS TEMPERATURES

Sample	Reaction Temperatu e	Residence Time	Product (Composition,	Mole \$
No.	*c	Second	SiH ₂ Cl ₂	SiHC13	SiCl ₄
I	500	148	0.3726	22.29	77.33
I	500	148	0.3596	21.98	77.66
I	500	148	0.3779	22.15	77.47
I	500	148	0.3600	22,11	77.53
		Average =	0.3675	22,13	77.50
II	525	138	0.4781	23.25	76.27
II	525	138	0.3651	22.98	76.66
II	525	138	0.4141	22.92	76.66
II	525	138	0.4359	22.93	76.64
		Average =	0.4233	23.02	76.56
III	550	101	0.5750	24.05	75.38
III	550	101	0.5125	23.98	75.51
III	550	101	0.5099	24.21	75.28
III	550	101	0.5650	23.98	75.45
		Average =	0.5406	24.06	75.40
IA	575	98	0.5857	24.89	74.53
IV	<i>5</i> 7 <i>5</i>	98	0.5294	24.84	74.63
Ϊ́ν	575	98	0.5070	24.85	74.64
IV	575	98	0.4828	24.92	74.60
		Average =	0.5262	24.88	74.60

EQUILIBRIUM CONSTA TO FOR THE HYDROCHIORINATION OF SICLA AND M.G. SILICON AT 100 PSIG, $\rm H_2/SiCl_L=2.0$ AND AT VARIOUS TEMPERATURES TABLE II

	ť.	Atm1			ORIGI OF PO	nal Page Oor Quali	IS TY
	m Constar	К _р -4 д	5.83	7.14	9.01	10.7	
THE THE COURT OF T	Equilibrium Constant	x 10 ⁻³	4.55	5.57	7.03	8,35	
	mn	H2	0.63916	0.63786	0.63618	0.63513	
Trota /8:	at Equilibrium	Sici	0.27965	0.27725	0.27432	0.27218	
	Mole Fractions a	SiHCl3	0.079855	0,083363	0.087535	0.090774	
	Mole	SiH2Cl2	0.001326	0.001533	0.001967	0.001920	
	Reaction	D D	200	525	550	575	
	Expt'1	No.	н	II	III	IV	

EQUILIBRIUM CONSTANTS FOR THE HYDROCHLORINATION OF SICL AND M.G. SILICON AT 500°C, 100 PSIG AND AT VARIOUS H2/SIC14 FEED RATIOS TABLE III

		ORIGINAL PAGE IS OF POOR QUALITY											
n Constant v	x 10-3Atm1	0.617	0.587	0.599	0.665	969.0							
Equilibrium Constant	× 10-3	4.81	4.58	4.67	5.19	5.43							
ilibrium	Н2	0.8088	0.7825	0.7148	0.6392	0.4627							
Mole Fractions at Equilibrium	Sicly	0.1376	0.1594	0.2153	0.2785	0.4379							
Mole Frac	SiHCl3	0.05353	0.05806	0.06988	0.08225	0.09939							
Equilibrium (1) Composition	Sicly	72.0	73.3	75.5	77.2	81.5							
Equilib: Composi	Mole 9 SiHCl3	28.0	26.7	24.5	22.8	18.5							
H ₂		4.7	0.4	2.8	2.0	1.0							

(1) Data from Figure V, fourth Quarterly Report, April 9 to July 8, 1982.

Equilibrium constants for the hydrochlorination of ${\rm Sicl}_{\mu}$ and ${\rm M.G.}$ silicon at 500°C and at various pressures and ${\rm H_2/Sicl}_{\mu}$ feed ratios TABLE IV

							GINA POO					
Equilibrium Constant K K _p	x 10-3Atm.1	0.685	0.661	969.0	0,665	0.599	0.587	0.617	1.33	1.65	1.52	1.29
Equílíbr K	x 10-3	1.85	3.95	5.43	5.19	4.67	4.58	4,81	14.9	24.2	32.6	45.3
uilibrium	H ₂	8449.0	0.7155	0.4627	0.6392	0.7148	0.7825	0,8088	0.6325	0.6289	0.7041	0.7020
Fraction at Equilibrium	Sicly	0.2895	0.2170	0.4379	0.2785	0.2153	0.1594	0.1376	0.2650	0.2579	0.1923	0.1877
Mole Frac	SiHCl3	0.06572	0.06741	0.09939	0.08225	0.06988	0.05806	0.05353	0.1025	0.1132	0.1035	0.1102
orium Ition %	Sicl	81.5	76.3	81.5	77.2	75.5	73.3	72.0	72.1	69.5	65.0	63.0
	SiHCl3	18.5	23.7	18.5	22.8	24.5	26.7	28.0	27.9	30.5	35.0	37.0
$\frac{\mathrm{H}_2}{\mathrm{SiCl}_4}$	Ratio	2.0	8.8	1.0	2.0	2.8	0.4	4.7	2.0	2.0	2.8	2.8
tor sure	Atm.	2.70	5.97	7.80	7.80	7.80	7.80	7.80	11.2	14.6	21.4	35.0
Reactor Pressure	psig	25	73	100	100	100	100	100	150	200	300	500

SILICON AT 450°C AND AT VARIOUS PRESSURES AND H2/Sicl4 FEED RATIOS EQUILIBRIUM CONSTANTS FOR THE HYDROCHLORINATION OF SICI $_{f \mu}$ AND M.G. > TABLE

	-11			OR OF	IGINA POOI	L PAR R QU/	 ALITY			
Equilibrium Constant K K	x 10-3 tm.	0.364	0.345	0.382	0.601	0.627	0.854	0.764	1.19	199.0
Equilibr K	x 10 ⁻³	0.983	2.06	2.98	6.73	7.02	12.5	16.3	25.4	23.2
uilibrium	H,2	92490	0.7183	0.6424	0.6377	0.7128	0.6337	0.7083	0.4483	0.7062
Mole Fraction at Equilibrium	Sicl	0.2953	0.2231	0.2847	0.2754	0.2111	0.2674	0.2013	0.4138	0.1968
Mole Frac	SiHCl3	0.05708	0.05858	0.07296	0.08696	0.07611	06، 0	6,09043	0.1379	0.09695
orium Ition	Siclu	83.8	79.2	9.62	0.92	73.5	73.0	0.69	75.0	67.0
Equilibrium Composition	Sincl ₃	16.2	20.8	20.4	24.0	26.5	27.0	31.0	25.0	33.0
H ₂	Ratio	2.0	2.8	2.0	2.0	2.8	2.0	2.8	1.0	2.8
Reactor Pressure	Atm.	2.70	5.96	7.80	11.2	11.2	14.6	21.4	21.4	35.0
Reactor Pressur	psig	25	73	100	150	150	200	300	300	500

Pressure 114.7 psia, Temperature 500 °C, H₂/SiCl₄ Feed Ratio 4.7. THE HYDROCHLORINATION OF SICL $_{\mu}$ AND M.G. SILICON METAL TO SIHCL $_{3}$ TABLE VI

							PAGE QUALI	
Rate Constant k ₁	x 10-3sec1						12.7	
In x _e -x		1.180	1.653	2.063	2.422	3.158	_	
Equil. Partial Press.	x _e	1	ŧ	ı	ı	1	6.139	
Initial Partial Press.	21C L4	20.12	20.12	20.12	21 12	20.12	20.12	
Time taction	$\operatorname{sicl}_{m{\mu}}$	(17.12) 0.1493	(16.62) 0.1449	(16.34) 0.1424	(16.17) 0.1410	(15.97) 0.1393	(15.79) 0.1376	
mposition at Time (psia)/Mole Fraction	siHCl_3	(93.30) (4.250) 0.8137 0.03708	(4,964)	(5.359)	(5.594)	(5.878) 0.05124	(6.139) 0.5353	
Composition (psia)/Mo	H ₂	(93.30)	(93.12) 0.8118	(93.00) 0.8108	(92.93) 0.8102	(92.85) 0.8095	(92.77) 0.8088	
position Mole %	SiCl_{4}	80.1	77.0	75.3	24.3	73.1	72.0	
Composition Mole %	$\sin c_3 \sin a_4$	19.9	23.0	2.42	25.7	26.9	28.0	
Time t	sec.	10	20	30	04	09	Ŀq.	

Figure V, fourth Quarterly Report, April 9 - July 8, 1982. Reference To:

Pressure 114.7 psia, Temperature 500 °C, H2/SiCl4 Feed Ratio 4.0. THE HYDROCHLORINATION OF SICI $_{\mu}$ AND M.G. SILICON METAL TO SIHCI $_3$ TABLE VII

	·				·······		0	RIG E_P	il «M	L F	AC UA	C [Ť			
Rate	constant k1	x 10-3sec1								!				12.2	,	
×	ln x _e -x		4	1.058		1.518		1,909		2.337		3.114		1		
Equil.	Partial Press. Sinci	xe xe		ı		,		ı		1		ı	10/	600.0		
Initial	Partial Press. SiCl.	† d	1	22.94		22.94		22.94		22.94		22.94	000	46.22		
at Time t	Fraction	H_2 SiHCl ₃ SiCl _{μ}	(19.88)	0.1734	(19.29)	0.1681	(18.95)	0.1653	(18.71)	0.1631	(18.47)	0.1610	(18.26)	0.1592		
]	(psia)/Mole Fra	Sinci	(4.365)	0.03806	(5.220)	0.04551	(9.694)	0.04964	(6:039)	0.05265	(6.388)	0.05569	(6.685)	0.05829	,	
Composition	(psia	Н2	(90.45)	0.7886	(90.19)	0.7864	(90.05)	0.7851	(89.95)	0.7842	(88.84)	0.7833	(89.75)	0.7825		
Composition	Mole %		!	0.20	i	78.7		76.9	1	75.0	-1-6	74.3	0	13.6		
Compos	Mo	Sincl ₃ Sicl ₄	0	10.0	•	21.3		23.1	-	74.42	,	25.7	0 70	0.02		
Time	₽	sec.		OT	,	20	,	30		040		09	ţ	• ba		

Reference To: Figure V, fourth Quarterly Report, April 9 - July 8, 1982.

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Rate Constant k1	x 10 ⁻³ sec. ⁻¹						11.4	
ln $\frac{x_e}{x_e-x}$		1.128	1.587	2.030	2.483	3.227	-	
Equil. Partial Press.	x _e	ŧ	-	-	ı		8.015	
Initial Partial Press.	# e	30.18	30.18	30.18	30.18	30.18	30.18	
Time t	$\operatorname{sicl}_{\boldsymbol{\mu}}$	(26.47)	(25.82) 0.2251	(25.42) 0.2216	(25.16) 0.2193	(24.92) 0.2172	(24.70) 0.2153	
mposition at Time (psia)/Mole Fraction	\sin^2	(5.422)	(6.375)	(6.962)	(2°346) 0°06404	(7.697)	(8.015) 0.06988	
Composition (psia)/	Н2	(82.80)	(82.50) 0.7193	(82.32) 0.7177	(82.20) 0.7166	(82.08) 0.7156	(81.98) 0.7148	
Composition Mole %	$\sin c_3 \sin t_4$	83.0	80.2	78.5	77.4	76.3	75.5	
Comp	Sinci	17.0	19.8	21.5	22.6	23.7	24.5	
Time t	sec.	10	20	30	04	09	. <u>B</u> q.	

Pressure 114.7 psia, Temperature 500 °C, H₂/SiCl_{μ} Feed Ratio 2.8.

TABLE VIII THE HYDROCHLORINATION OF SICL $_{m \mu}$ AND M.G. SILICON METAL TO SIHCL $_{m 3}$

Reference To: Figure V, fourth Quarterly Report, April 9 - July 8, 1982.

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T 10-3 sec. Constant 10.9 Rate °C, H₂/SiCl₄ Feed Ratio 2.0 × x - a ×_{o)} 1.496 1.896 2.268 3.156 1.034 ı ቯ Equil. Partial SiHCla Press. 9.434 × ı ı ı ŧ ł Initial Partial Press. SiCl_{4} 38.23 38.23 38.23 38.23 38.23 38.23 ಡ Pressure 114.7 psia, Temperature 500 $\operatorname{SiCl}_{\mu}$ (32.60)(31.94)(34.18)(33.35)(32.89)(32.21)0.2842 0.2808 0.2908 0.2785 0.2980 0.2867 (psia)/Mole Fraction Time at Sincla 0.06383 0.06990 0.07373 0.07875 0.08225 0.05300 (6.02)(7.321)(8.018)(9.032)(8.457) (6.434) Composition (44.46) (24.03)(73.79)(93.46)(73.65)(73.32)0.6433 0.6404 0.6393 0649.0 0.6454 0.6421 H₂ 6.48 79.4 $\operatorname{SiCl}_{m{\mu}}$ 82.0 80.4 78.1 77.2 Composition Mole % Sincla 22.8 18.0 15.1 19.6 20.6 21.9 Time sec. Eq. 10 9 20 30 40

THE HYDROCHLORINATION OF SICIL AND M.G. SILICON METAL TO SIHCL $_3$

ΙX

TABLE

Figure V, fourth Quarterly Report, April 9 -July 8, 1982. Reference To:

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Rate Constant k ₁	x 10 ⁻³ sec1						9.30	
ln xe xe)	1.061	1,541	1.955	2,338	3,368	ŧ	
Equil. Partial Press.	SiHCl ₃ x _e	•	l	ı	1	l	11,	•
Initial Partial Press.	$\operatorname{SiCl}_{\mu}$	57.35	57.35	57.35	57.35	57.35	57.35	
Time taction	sicl_{4}	(52.61)	(51.65) 0.4503	(51.23) 0.4457	(50.80) 0.4429	(50.35)	(50.10) 0.4368	
at le Fra	sikcl3	(7.584)	(9.115) 0.07947	(9.957) 0.08681	(10.48) 0.09136	(11.20) 0.09767	(11.60) 0.1011	
Composition (psia)/Mol	H2	(54.51)	(53.93)	(53.62)	(53.42)	(53.15) 0.4634	(53.00)	
Composition Mole %	SiHCl ₃ SiCl ₄	4.78	85.0	83.7	82.9	81.8	81.2	
Compc	Sinci	12.6	15.0	16.3	17.1	18.2	18.8	
Time t	sec.	10	20	30	047	09	Eq.	

Pressure 114.7 psia, Temperature 500 °C, H2/SiCl4 Feed Ratio 1.0

THE HYDROCHLORINATION OF SICILLA AND M.G. SILICON METAL TO SIHCL $_3$

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TABLE

Figure V, fourth Quarterly Report, April 9 - July 8, 1982. Reference To:

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TABLE X I RATE CONSTANTS FOR THE HYDROCHLORINATION OF SiCl₄ AT 100 PSIG, 500 °C AS A FUNCTION OF H₂/SiCl₄ FEED RATIO

H ₂ /SiCl ₄ Feed	Equilibrium C Mole #	_	Rate Constant k ₁
Ratio	SiHC13	sic1 ₄	x 10 ⁻³ Sec. ⁻¹
4.7	28.0	72.0	12.7
4.0	26.8	73.2	12.2
2.8	24.5	75.5	11.4
2.0	22.8	77.2	10.9
1.0	18.8	81.2	9.30

Pressure 39.7 psia, Temperature 500 °C, $H_2/SiCl_4$ Feed Ratio 2.0. THE HYDROCHLORINATION OF SICL, AND M.G. SILICON METAL TO SIHCL $_3$

TABLE XII

							ilinal i	•
Rate Constant K ₁	x 10 ⁻³ sec1						14.5	
ln x _e -x		1.636	5.449	3.073	3.767	5.222	ŧ	
Equil. Partial Press.	SiHCl3 xe	1	-	l	•	•	765.2	•
Initial Partial Press.	Sic14	13.23	13.23	13.23	13.23	13.23	13.23	
Time t ction	${\tt sicl}_{m t}$	(11.84) 0.2983	(11.65) 0.2935	(11.58) 0.2918	(11.54) 0.2908	(11.51) 0.2900	(11.50) 0.2898	
at Le Fra	SiHC13	(2.089)	(2.370)	(2.474)	(2.534)	(2,580)	(2.594)	
Composition (psia)/Mol	Н2	(25.77)	(25.68) 0.6468	(25.64)	(25.62) 0.6454	(25.61) 0.6450	(25.60)	
Composition Mole %	Sicl4	85.0	83.1	82.4	82.0	81.7	81.6	
Compos Mol	SiHCl ₃ SiCl ₄	15.0	16.9	9.	0.1	18.3	18.4	
I'me t	sec.	10	2	36	0 7	09	•ba	

Reference To: Figure III, fourth Quarterly Report, April 9 - July 8, 1982.

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						JF PO(on Qu	WILLY,	
Rate	constant k1	x 10 ⁻³ sec1						12.2	
×	ln xe-x		0.7193	1.500	1.964	2,366	3.160	-	
Equil.	Press.	C+		ŧ	1	•	•	624.6	
Initial	Press.	± d 1 d	38.23	38.23	38.23	38.23	38.23	38.23	
Time t	ction	$\operatorname{SiCl}_{oldsymbol{\mu}}$	(34.99)	(33.32)	(32.80) 0.2860	(32.51) 0.2834	(31,18) 0,2806	(31.91) 0.2782	,
at	(psia)/Mole Fraction	SiHC13	(4.862)	(7.365)	(8.149) 0.07105	(8.589) 0.07488	(9.077) 0.07914	(9,479) 0.13264	
Composition	(psia)	н ₂	(74.85)	(74.01)	(73.75) 0.6430	(73.60) 0.6417	(73.44)	(73.31) 0.6391	
ition	₽	$\operatorname{SiCl}_{oldsymbol{\psi}}$	87.8	81.9	80.1	79.1	78.0	77.1	
Composition	Mole &	Sincl ₃ Sicl ₄	12.2	18.1	19.9	6*02	22.0	22.9	
Time	4	sec.	10	20	30	04	09	. pā	

XIII THE HYDROCHLORINATION OF SICL $_{m{\mu}}$ AND M.G. SILICON METAL TO SIHCL $_{m{3}}$

TABLE

Pressure 114.7 psia, Temperature 500 °C, H2/SiCl4 Feed Ratio

1982. Figure III, fourth Quarterly Report, April 9 - July 8, Reference To:

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Rate Constant	k ₁	x 10-3sec1												8.33		
×	x - ex			0.5925		1.059		1.447		1.884		2.865		ı		
Equil. Partial	Press.	×		ß		ſ		1		ı		ı		24.74		
Initial Partial	Press. S1C1,	* «		71.57		71.57		71.57		71.57		71.57		71.57		
Time t	1070	Sic14	(64.19)	0.2990	(60.09)	0.2832	(58.95)	0.2746	(57.58)	0.2682	(56.02)	0.2609	(55.07)	0.2565		
mposition at Time	T. more ris	$\mathbf{s_{1HC1}}_{\mathfrak{I}}$	(11.06)	0.05152	(16,16)	0.07527	(18.92)	0.08814	(20.98)	0.09769	(23.33)	0.1087	(54.74)	0.1152		
Composition	ot od \	Ж2	(139.4)	0.6495	(137.7)	0.6416	(136.8)	0.6373	(136.1)	0.6341	(1,55.4)	0.6305	(134.9)	0.6282		
Composition Mole 4	2	$\sin^2\sin^4$		85.3		0.62		75.7		73.3		9.02		69.0		
Compc		SiHCI	14.7		21.0		24.3		,	26.7		4.62		31.0		
Time	>	sec.		20	0.3	9		60		80	000	120		Eq.		

THE HYDROCHLORINATION OF SICI $_{oldsymbol{\mu}}$ AND M.G. SILICON METAL TO SIHCI $_{oldsymbol{\beta}}$

TABLE XIV

Pressure 214.7 psia, Temperature 500 °C, H2/SiCl4 Feed Ratio

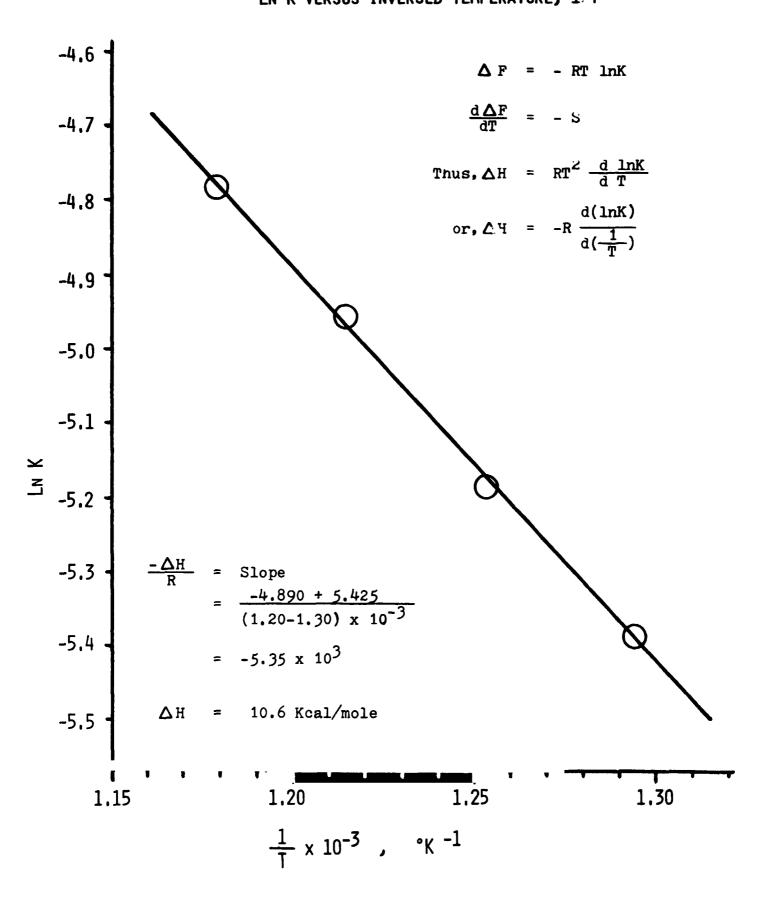
Figure III, fourth Quarterly Report, April 9 - July 8, 1982. Reference To:

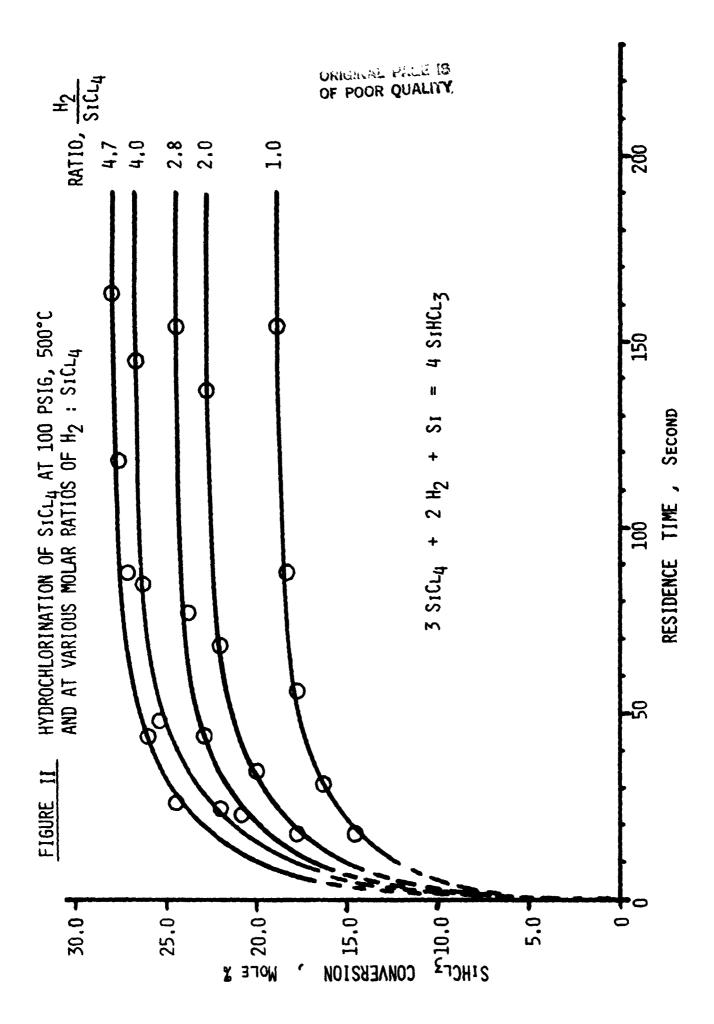
SUMMARY OF RATE CONSTANTS FOR THE HYDROCHLORINATION OF SiCl₄ AT 500 °C AS A FUNCTION OF REACTOR PRESSUR

React Press		H ₂ /SiCl ₄ Ratio	Equilib Mole		Rele Constant k ₁			
psig.	psig. Atm.		SiHC13	SiCl ₄	x 10 ⁻³ sec. ⁻¹			
25	2.70	2.0	18.4	81.6	14.5			
73	5.97	2.8	23.4	76.6	13.0			
100	7.80	2.0	22.9	77.1	12.2			
200	14.6	2.0	31.0	69.0	8.33			
500	35.0	2.8	37.5	62.5	7.06			

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FIGURE I PLOT OF THE VAN'T HOFF EQUATION LN K VERSUS INVERSED TEMPERATURE, 1/T





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FIGURE III PLOT OF THE PSUEDO-FIRST ORDER RATE EQUATION

FOR THE HYDROCHLORINATION OF SiCl, AT

100 PSIG. 500 °C AND H_/SiCl, RATIO 4.7

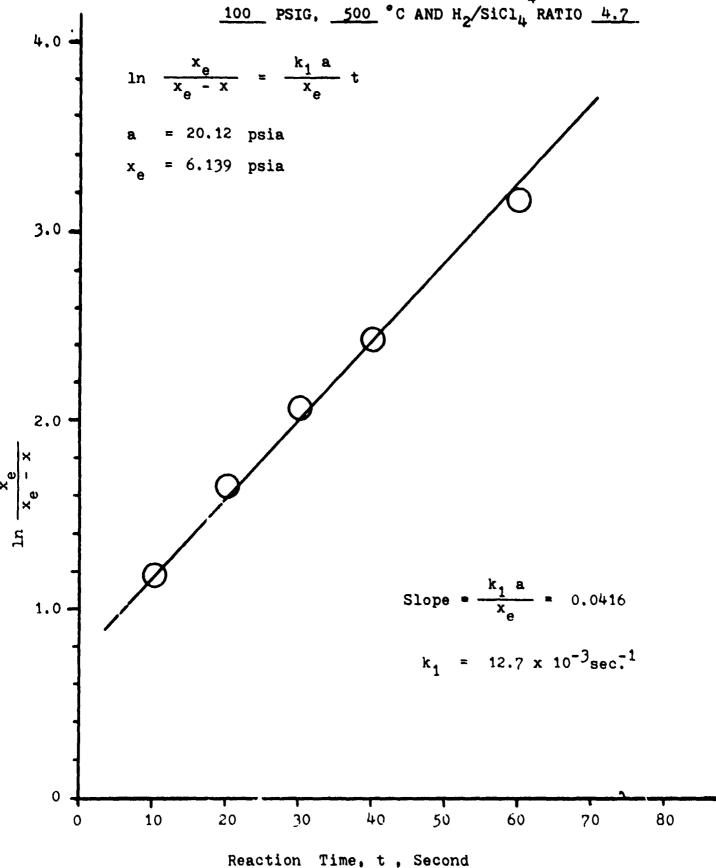


FIGURE PLOT OF THE PSUEDO-FIRST ORDER RATE EQUATION FOR THE HYDROCHLORINATION OF SiCl₄ AT

100 PSIG, 500 °C AND H₂/SiCl₄ RATIO 4.0 $\ln \frac{x_e}{x_e - x} = \frac{k_1 a}{x_e} t$ a = 22.94 psia $x_e = 6.685 \text{ psia}$ Slope = $\frac{k_1}{x_e}$ = 0.0418 1.0 $k_1 = 12.2 \times 10^{-3} \text{sec.}^{-1}$ 0 10 40 50 60 20 30 70 80 0

Reaction Time, t, Second

FIGURE PLOT OF THE PSUEDO-FIRST ORDER RATE EQUATION FOR THE HYDROCHLORINATION OF SiCl₄ AT

100 PSIG, 500 °C AND H₂/SiCl₄ RATIO 2.8 $\ln \frac{x_e}{x_e - x} = \frac{k_1 a}{x_e} t$ = 30.18 psia = 8.015 psia ORIGINAL PROTEIN OF POOR QUALITY Slope = $\frac{k_1}{x_e} = 0.0428$ $k_1 = 11.4 \times 10^{-3} \text{sec}^{-1}$ 0 60 40 50 10 20 80 0 30 70

Reaction Time, t, Second

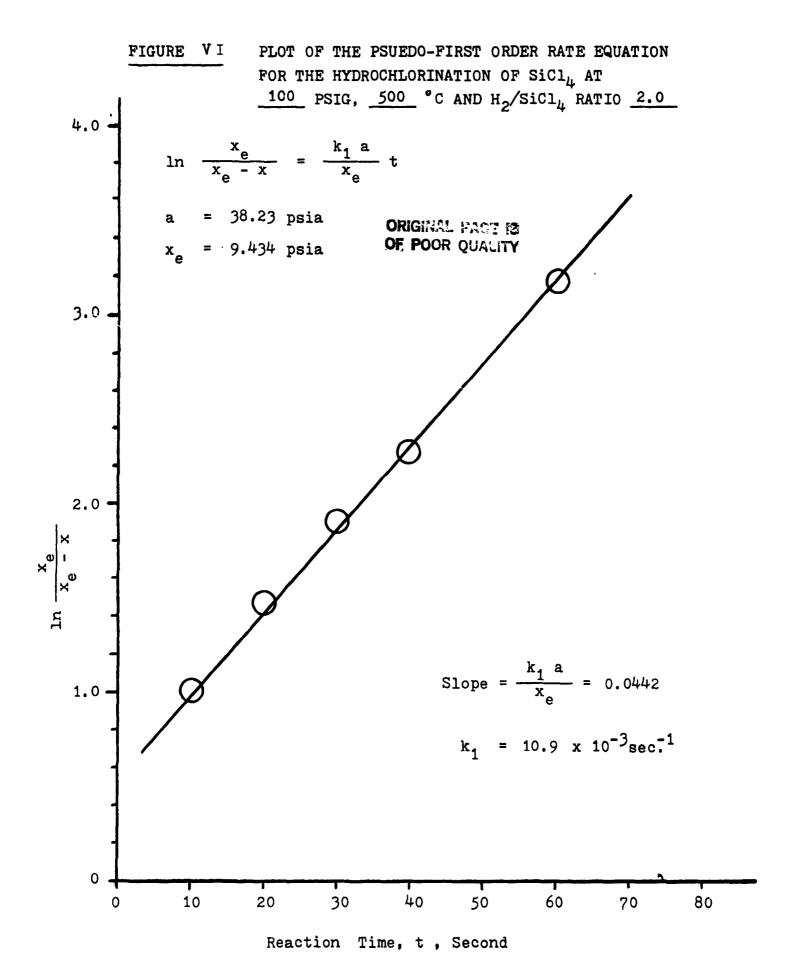
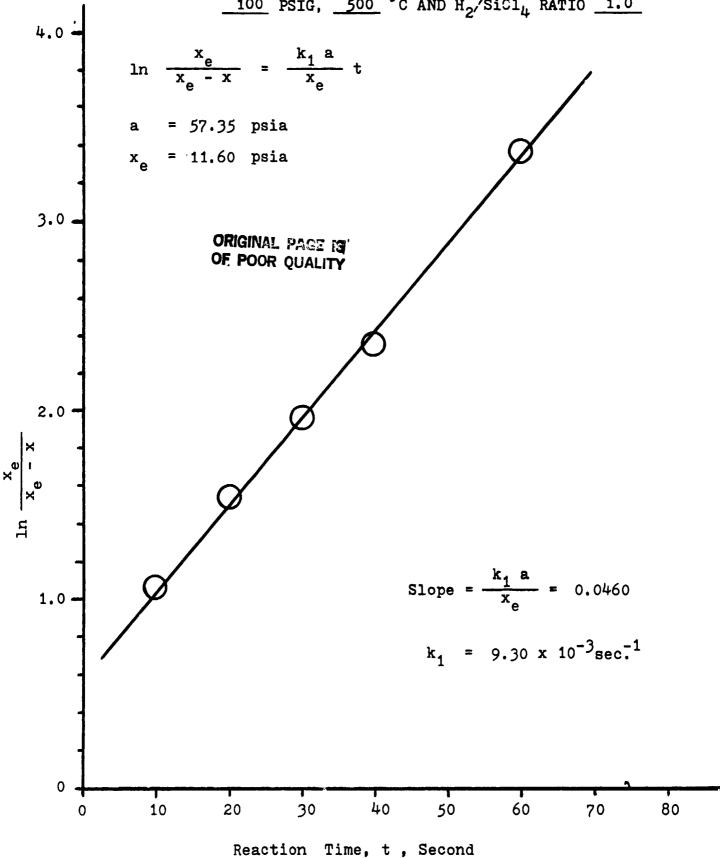


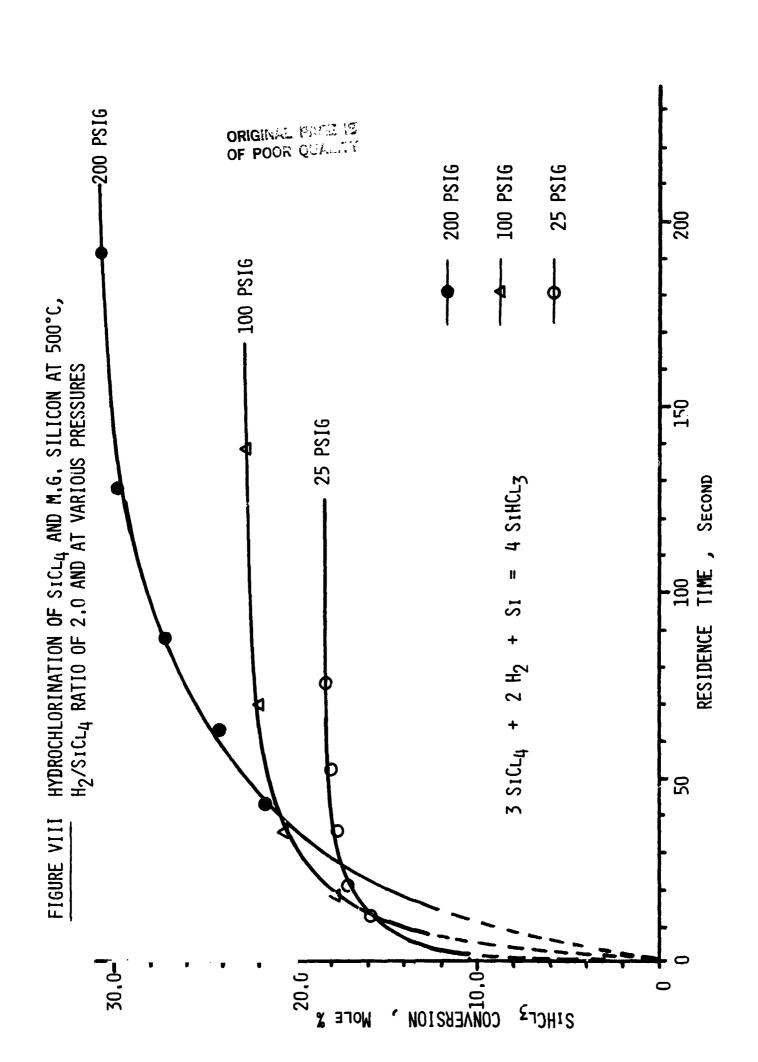
FIGURE VII

PLOT OF THE PSUEDO-FIRST ORDER RATE EQUATION

FOR THE HYDROCHLORINATION OF SiCl₄ AT

100 PSIG, 500 °C AND H₂/SiCl₄ RATIO 1.0





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FIGURE IX PLOT OF THE PSUEDO-FIRST ORDER RATE EQUATION

FOR THE HYDROCHLORINATION OF SICL₄ AT 25 PSIG

500 °C AND H₂/SiCl₄ FEED RATIO OF 2.0

Reaction Time, t, Second

